

2333 STATIC READ ONLY MEMORY (4096x8)

DESCRIPTION

The 2333 high performance read only memory is organized 4096 words by 8 bits with access times of less than 350 ns. This ROM is designed to be compatible with all microprocessor and similar applications where high performance, large bit storage and simple interfacing are important design considerations. This device offers TTL input and output levels.

The 2333 operates totally asynchronously. No clock input is required. The two programmable chip select inputs allow four 32K ROMs to be OR-tied without external decoding.

Designed to replace two 2716 16K EPROMs, the 2333 can eliminate the need to redesign printed circuit boards for volume mask programmed ROMs after prototyping with EPROMs.

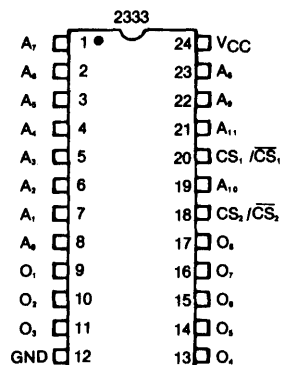
- 4096 x 8 Bit Organization
- Single +5 Volt Supply
- Three Week Prototype Turnaround
- Access Time—2333 450 ns
2333A 350 ns
- Completely TTL Compatible
- Totally Static Operation
- Three-State Outputs for Wire-OR Expansion
- Two Programmable Chip Selects
- Pin Compatible with 2716 & 2732 (INTEL) EPROMs
- Replacement for Two 2716s
- 2708/2716 EPROMs Accepted as Program Data Inputs
- 400 mV Noise Immunity on Inputs

ORDERING INFORMATION:

Part Number*	Package Type	Access Time	Temperature Range
MPS2333	Molded	450 ns	0°C to +70°C
MPS2333A	Molded	350 ns	0°C to +70°C
MCS2333	Ceramic	450 ns	0°C to +70°C
MCS2333A	Ceramic	350 ns	0°C to +70°C

*Final Part Number will be assigned by manufacturer

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS

Ambient Operating Temperature	0° to +70°C
Storage Temperature	-65°C to +150°C
Supply Voltage to Ground Potential	-0.5V to +7.0V
Applied Output Voltage	-0.5V to +7.0V
Applied Input Voltage	-0.5V to +7.0V
Power Dissipation	1.0W

COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

D.C. CHARACTERISTICS

$T_A = 0^\circ\text{C to } +70^\circ\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$ (unless otherwise specified)

Symbol	Parameter	Min.	Max.	Units	Test Conditions
I_{CC1}	Power Supply Current		125	mA	$V_{IN} = V_{CC}$, $V_O = \text{Open}$, $T_A = 0^\circ\text{C}$
I_{CC2}	Power Supply Current		120	mA	$V_{IN} = V_{CC}$, $V_O = \text{Open}$, $T_A = 25^\circ\text{C}$
I_O	Output Leakage Current		10	μA	Chip Deselected, $V_O = 0$ to V_{CC}
I_I	Input Load Current		10	μA	$V_{CC} = \text{Max.}$, $V_{IN} = 0$ to V_{CC}
V_{OL}	Output Low Voltage		0.4	Volts	$V_{CC} = \text{Min.}$, $I_{OL} = 2.1\text{mA}$
V_{OH}	Output High Voltage	2.4		Volts	$V_{CC} = \text{Min.}$, $I_{OH} = -400\mu\text{A}$
V_{IL}	Input Low Voltage	-0.5	0.8	Volts	See note 1
V_{IH}	Input High Voltage	2.0	$V_{CC} + 1$	Volts	

A. C. CHARACTERISTICS

$T_A = 0^\circ\text{C to } +70^\circ\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$ (unless otherwise specified)

Symbol	Parameter	2333		2333A		Units	Test Conditions
		Min.	Max.	Min.	Max.		
t_{ACC}	Address Access Time		450		350	ns	See Note 2
t_{CO}	Chip Select Delay		200		200	ns	
t_{DF}	Chip Deselect Delay		175		175	ns	
t_{OH}	Previous Data Valid After Address Change Delay	40		40		ns	

CAPACITANCE

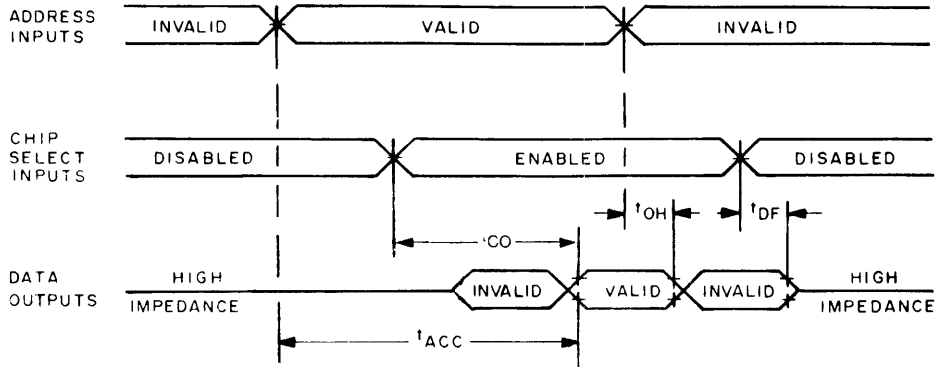
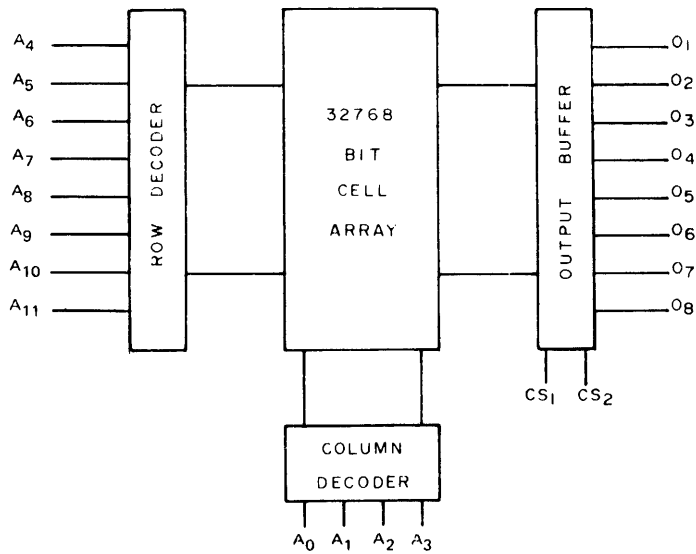
$T_A = 25^\circ\text{C}$, $f = 1.0\text{MHz}$, See Note 3

Symbol	Parameter	Min.	Max.	Units	Test Conditions
C_{IN}	Input Capacitance		8	pF	All Pins except Pin under Test Tied to AC Ground
C_{OUT}	Output Capacitance		10	pF	

Note 1: Input levels that swing more negative than -0.5V will be clamped and may cause damage to the device.

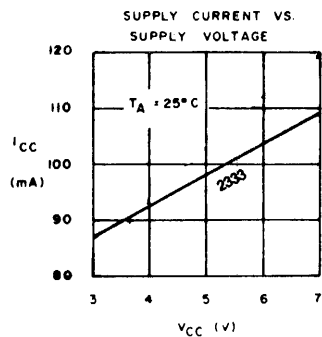
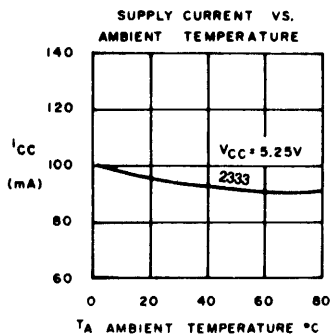
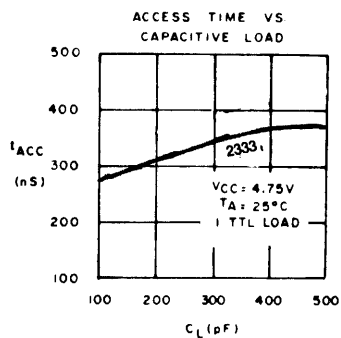
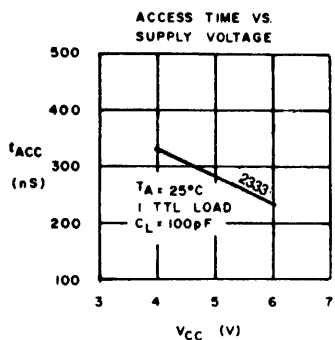
Note 2: Loading 1 TTL + 100 pF, input transition time: 20 ns.
Timing measurement levels: input 1.5V, output 0.8V and 2.0V. $C_L = 100\text{pF}$.

Note 3: This parameter is periodically sampled and is not 100% tested.

TIMING DIAGRAM

BLOCK DIAGRAM


COMS

TYPICAL CHARACTERISTICS



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